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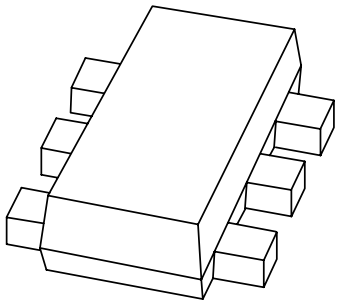
Team Nexperia

DATA SHEET



PMEG2005AEV; PMEG3005AEV; PMEG4005AEV

Very low V_F MEGA Schottky barrier rectifiers

Product data sheet

2003 Aug 20

Very low V_F MEGA Schottky barrier rectifiers

PMEG2005AEV; PMEG3005AEV; PMEG4005AEV

FEATURES

- Very low forward voltage
- High surge current
- Ultra small plastic SMD package.

APPLICATIONS

- Low voltage rectification
- High efficiency DC/DC conversion
- Voltage clamping
- Inverse polarity protection
- Low power consumption applications.

DESCRIPTION

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOT666 ultra small SMD plastic package.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
I_F	forward current	0.5	A
V_R	reverse voltage		
	PMEG2005AEV	20	V
	PMEG3005AEV	30	V
	PMEG4005AEV	40	V

PINNING

PIN	DESCRIPTION
1	cathode
2	cathode
3	anode
4	anode
5	cathode
6	cathode

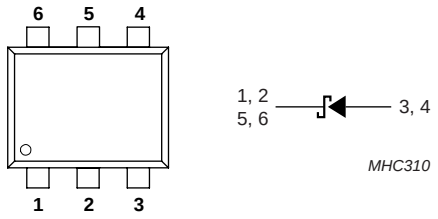


Fig.1 Simplified outline (SOT666 and symbol).

MARKING

TYPE NUMBER	MARKING CODE
PMEG2005AEV	G1
PMEG3005AEV	G2
PMEG4005AEV	G3

RELATED PRODUCTS

TYPE NUMBER	DESCRIPTION	FEATURE
PMEGxx05AEA	0.5 A; 20/30/40 V very low V_F MEGA Schottky rectifier	SOD323 (SC-76) package
PMEG2005EB	0.5 A; 20 V very low V_F MEGA Schottky rectifier	SOD523 (SC-79) package
PMEG2010EA	1 A; 20 V very low V_F MEGA Schottky rectifier	higher forward current

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage				
	PMEG2005AEV		–	20	V
	PMEG3005AEV		–	30	V
	PMEG4005AEV		–	40	V
I_F	continuous forward current	note 1	–	0.5	A
I_{FRM}	repetitive peak forward current	$t_p \leq 1$ ms; $\delta \leq 0.5$; note 2	–	3.5	A
I_{FSM}	non-repetitive peak forward current	$t_p = 8$ ms; square wave; note 2	–	10	A
T_j	junction temperature	note 3	–	150	°C
T_{amb}	operating ambient temperature	note 3	−65	+150	°C
T_{stg}	storage temperature		−65	+150	°C

Notes

1. Refer to SOT666 standard mounting conditions.
2. Only valid if pins 3 and 4 are connected in parallel.
3. For Schottky barrier diodes thermal runaway has to be considered, as in some applications, the reverse power losses (P_R) are a significant part of the total power losses. Nomograms for determination of the reverse power losses P_R and $I_{F(AV)}$ rating will be available on request.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	in free air; notes 1 and 2	405	K/W
		in free air; notes 2 and 3	215	K/W
$R_{th\ j\text{-}s}$	thermal resistance from junction to soldering point	note 4	80	K/W

Notes

1. Refer to SOT666 standard mounting conditions.
2. For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determination of the reverse power losses P_R and $I_{F(AV)}$ rating will be available on request.
3. Device mounted on an FR4 printed-circuit board with copper clad 10 × 10 mm.
4. Solder point of cathode tab.

ELECTRICAL CHARACTERISTICS

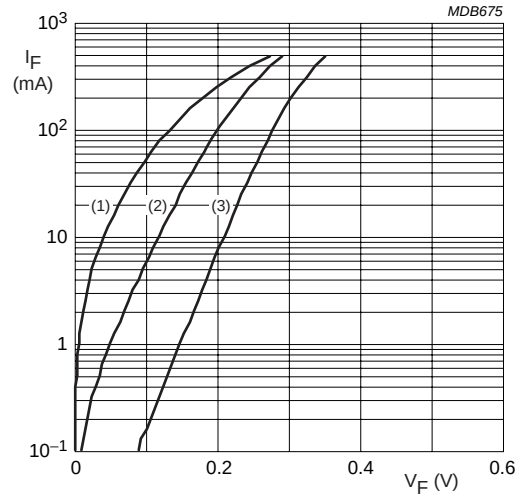
T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	PMEG2005AEV		PMEG3005AEV		PMEG4005AEV		UNIT
			TYP.	MAX.	TYP.	MAX.	TYP.	MAX.	
V_F	forward voltage	I_F = 0.1 mA	90	130	90	130	95	130	mV
		I_F = 1 mA	150	190	150	200	155	210	mV
		I_F = 10 mA	210	240	215	250	220	270	mV
		I_F = 100 mA	280	330	285	340	295	350	mV
		I_F = 500 mA	355	390	380	430	420	470	mV
I_R	continuous reverse current	V_R = 10 V; note 1	15	40	12	30	7	20	μA
		V_R = 20 V; note 1	40	200	–	–	–	–	μA
		V_R = 30 V; note 1	–	–	40	150	–	–	μA
		V_R = 40 V; note 1	–	–	–	–	30	100	μA
C_d	diode capacitance	V_R = 1 V; f = 1 MHz	66	80	55	70	43	50	pF

Note

1. Pulse test: $t_p \leq 300$ μs; $\delta \leq 0.02$.

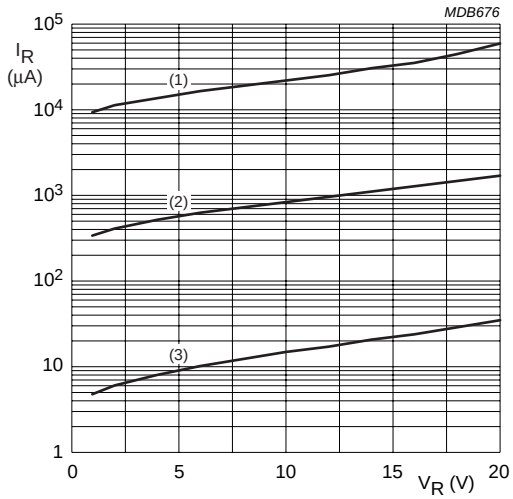
GRAPHICAL DATA



PMEG2005AEV

(1) T_{amb} = 150 °C.
(2) T_{amb} = 85 °C.
(3) T_{amb} = 25 °C.

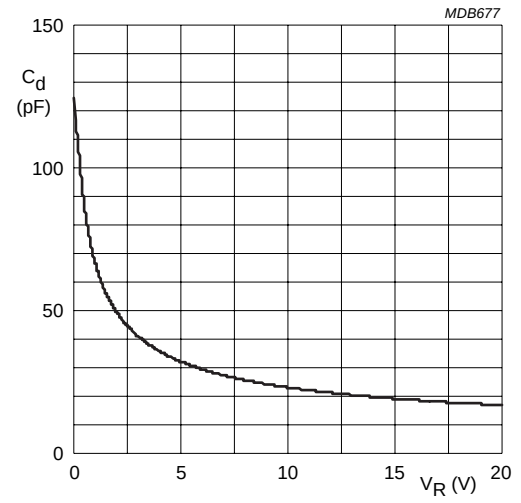
Fig.2 Forward current as a function of forward voltage; typical values.



PMEG2005AEV

(1) T_{amb} = 150 °C.
(2) T_{amb} = 85 °C.
(3) T_{amb} = 25 °C.

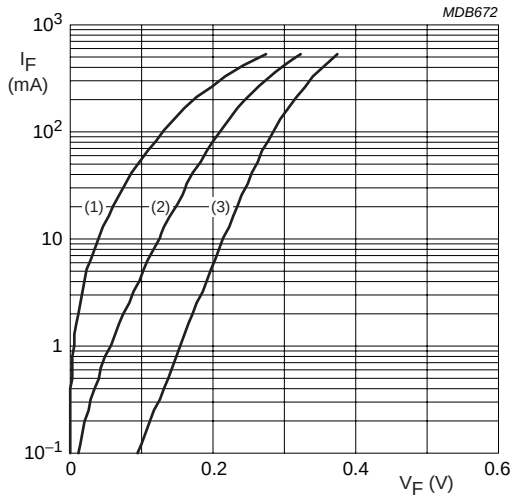
Fig.3 Reverse current as a function of reverse voltage; typical values.



PMEG2005AEV

f = 1 MHz; T_{amb} = 25 °C.

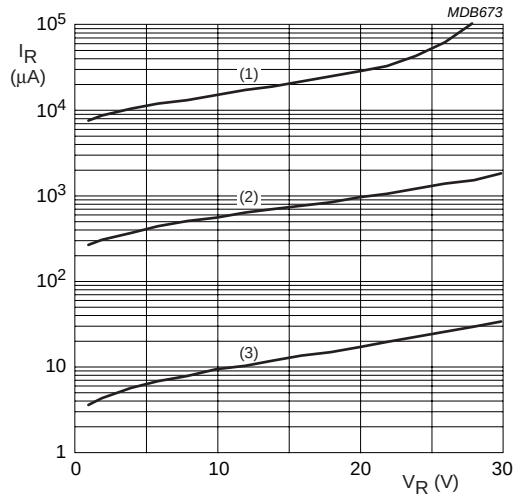
Fig.4 Diode capacitance as a function of reverse voltage; typical values.



PMEG3005AEV

(1) T_{amb} = 150 °C.
(2) T_{amb} = 85 °C.
(3) T_{amb} = 25 °C.

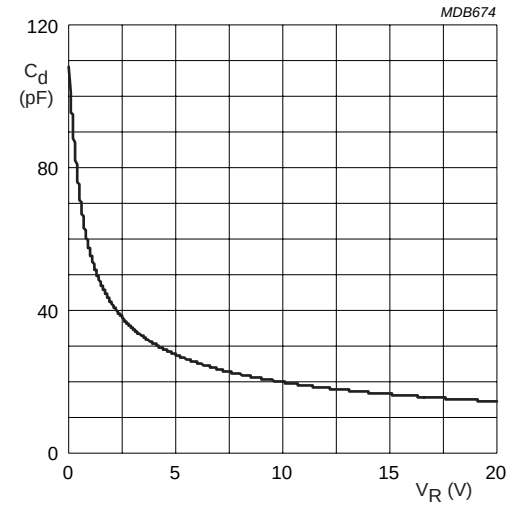
Fig.5 Forward current as a function of forward voltage; typical values.



PMEG3005AEV

(1) T_{amb} = 150 °C.
(2) T_{amb} = 85 °C.
(3) T_{amb} = 25 °C.

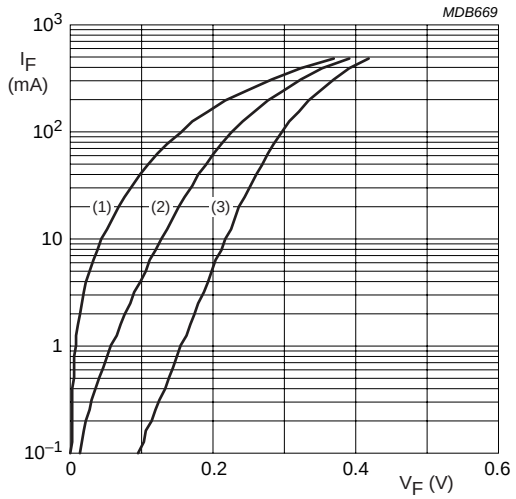
Fig.6 Reverse current as a function of reverse voltage; typical values.



PMEG3005AEV

f = 1 MHz; T_{amb} = 25 °C.

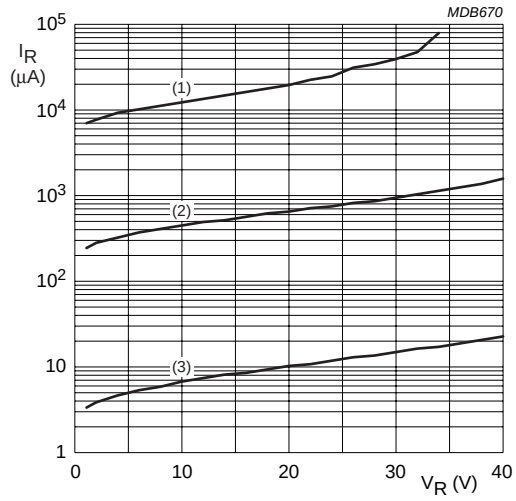
Fig.7 Diode capacitance as a function of reverse voltage; typical values.



PMEG4005AEV

(1) T_{amb} = 150 °C.
(2) T_{amb} = 85 °C.
(3) T_{amb} = 25 °C.

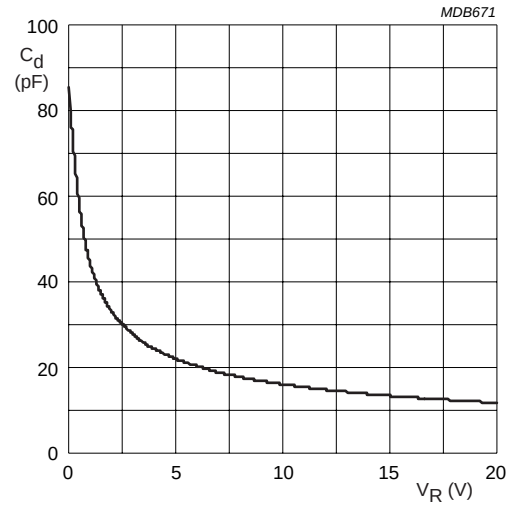
Fig.8 Forward current as a function of forward voltage; typical values.



PMEG4005AEV

(1) T_{amb} = 150 °C.
(2) T_{amb} = 85 °C.
(3) T_{amb} = 25 °C.

Fig.9 Reverse current as a function of reverse voltage; typical values.



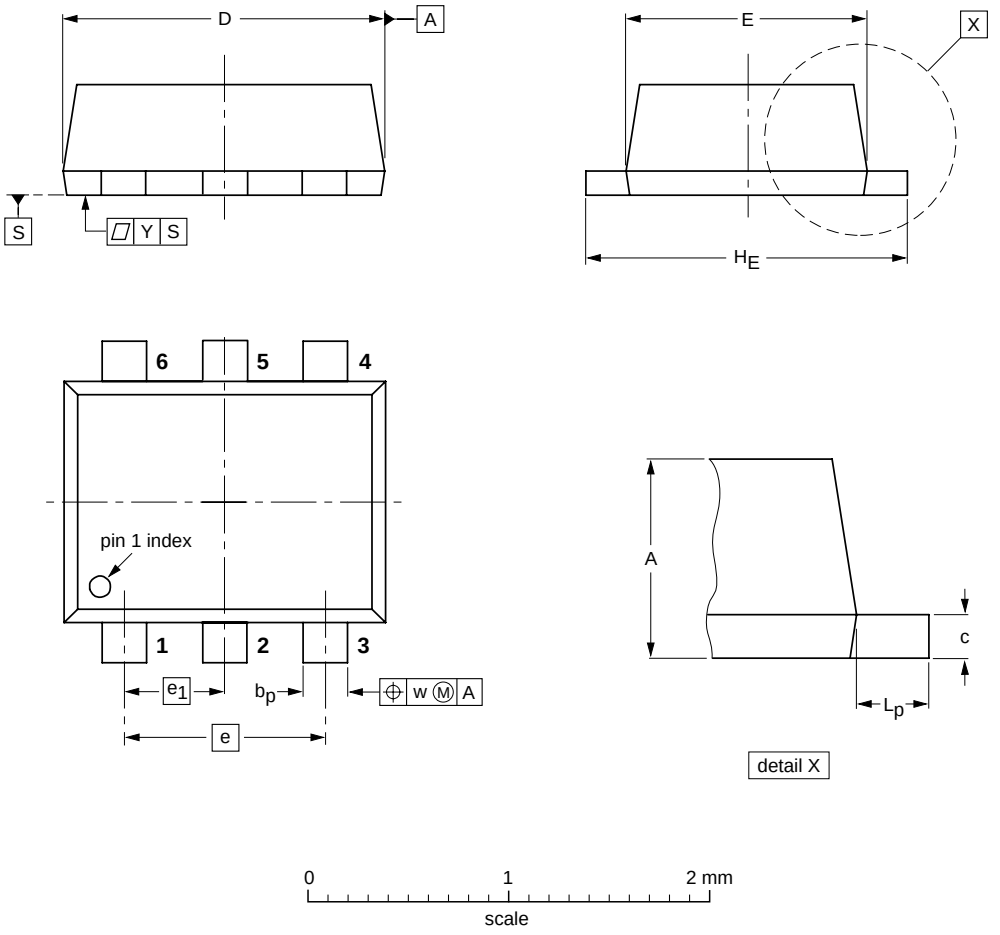
PMEG4005AEV

f = 1 MHz; T_{amb} = 25 °C.

Fig.10 Diode capacitance as a function of reverse voltage; typical values.

PACKAGE OUTLINE

Plastic surface mounted package; 6 leads **SOT666**



DIMENSIONS (mm are the original dimensions)

UNIT	A	b_p	c	D	E	e	e_1	H_E	L_p	w	y
mm	0.6 0.5	0.27 0.17	0.18 0.08	1.7 1.5	1.3 1.1	1.0	0.5	1.7 1.5	0.3 0.1	0.1	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT666						~~01-01-04~~ 01-08-27

DATA SHEET STATUS

DOCUMENT STATUS[1]	PRODUCT STATUS[2]	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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NXP Semiconductors

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Contact information

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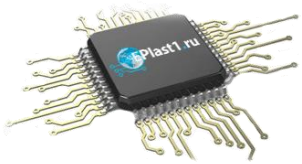

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